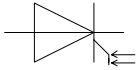

**Netz-Thyristor**  
**Phase Control Thyristor**
**T1503N**
**Elektrische Eigenschaften / Electrical properties**  
 Höchstzulässige Werte / Maximum rated values

Periodische Rückwärts-Spitzensperrspannung repetitive peak and reverse voltages	$T_{vj} = -40^{\circ}\text{C} \dots T_{vj \text{ max}}$	$V_{RRM}$	7500	8000	V V
Periodische Rückwärts-Spitzensperrspannung repetitive peak reverse voltages	$T_{vj} = 0^{\circ}\text{C} \dots T_{vj \text{ max}}$	$V_{RRM}$	7700	8200	V V
Durchlaßstrom-Grenzeffektivwert maximum RMS on-state current		$I_{TRMSM}$		3800	A
Dauergrenzstrom average on-state current	$T_C = 85^{\circ}\text{C}$ $T_C = 60^{\circ}\text{C}$	$I_{TAVM}$		1760 2440	A A
Stoßstrom-Grenzwert surge current	$T_{vj} = 25^{\circ}\text{C}, t_p = 10 \text{ ms}$ $T_{vj} = T_{vj \text{ max}}, t_p = 10 \text{ ms}$	$I_{TSM}$		45000 40000	A A
Grenzlastintegral $I^2t$ -value	$T_{vj} = 25^{\circ}\text{C}, t_p = 10 \text{ ms}$ $T_{vj} = T_{vj \text{ max}}, t_p = 10 \text{ ms}$	$I^2t$		10100 8000	$10^3 \text{ A}^2\text{s}$ $10^3 \text{ A}^2\text{s}$
Kritische Stromsteilheit critical rate of rise of on-state current	DIN IEC 60747-6 $f = 50 \text{ Hz}, P_{LM} = 40\text{mW}, t_{rise} = 0,5\mu\text{s}$	$(di_T/dt)_{cr}$		300	A/ $\mu\text{s}$
Kritische Spannungssteilheit critical rate of rise of off-state voltage	$T_{vj} = T_{vj \text{ max}}, V_D = 0,67 V_{DRM}$ 5.Kennbuchstabe / 5 <sup>th</sup> letter H	$(dv_D/dt)_{cr}$		2000	V/ $\mu\text{s}$

## Charakteristische Werte / Characteristic values

Schutzzündspannung (statisch) Protective break over voltage	$T_{vj} = 0^{\circ}\text{C} \dots T_{vj \text{ max}}$	$V_{BO}$	min.	7500	V
Durchlaßspannung on-state voltage	$T_{vj} = T_{vj \text{ max}}, i_T = 4000\text{A}, V_D = 100\text{V}$	$v_T$	typ. max.	2,8 3,0	V V
Schleusenspannung threshold voltage	$T_{vj} = T_{vj \text{ max}}$	$V_{(TO)}$	typ. max.	1,20 1,24	V V
Ersatzwiderstand slope resistance	$T_{vj} = T_{vj \text{ max}}$	$r_T$	typ. max.	0,4 0,44	m $\Omega$ m $\Omega$
Durchlaßkennlinie on-state characteristic  $v_T = A + B \cdot i_T + C \cdot \ln(i_T + 1) + D \cdot \sqrt{i_T}$	$T_{vj} = T_{vj \text{ max}}$	typ.  max.	A B C D  A B C D	0,616 0,000219 0,0342 0,0161  -0,0864 0,000343 0,2021 0,000614	
minimale Zündlichtleistung minimum gate trigger light power	$T_{vj} = 25^{\circ}\text{C}, V_D = 100\text{V}$	$I_{GT}$	max.	40	mW
Haltestrom holding current	$T_{vj} = 25^{\circ}\text{C}$	$I_H$	max.	100	mA
Einraststrom latching current	$T_{vj} = 25^{\circ}\text{C}, V_D = V,$ $P_{LM} = 40\text{mW}, t_{rise} = 0,5\mu\text{s}$	$I_L$	max.	1	A
Rückwärts-Sperrstrom reverse blocking current	$T_{vj} = T_{vj \text{ max}}$ $V_R = V_{RRM}$	$i_R$	max.	600	mA
Zündverzug gate controlled delay time	DIN IEC 60747-6 $T_{vj} = 25^{\circ}\text{C}, V_D = 1000\text{V},$ $P_{LM} = 40\text{mW}, t_{rise} = 0,5\mu\text{s}$	$t_{gd}$	max.	5	$\mu\text{s}$

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**Elektrische Eigenschaften / Electrical properties**  
 Charakteristische Werte / Characteristic values

Freiwerdezeit circuit commutated turn-off time	$T_{vj} = T_{vj\ max}$ , $i_{TM} = I_{TAVM}$ $V_{RM} = 100\ V$ , $v_{DM} = 0,67\ V_{DRM}$ $dv_D/dt = 20\ V/\mu s$ , $-di_T/dt = 10\ A/\mu s$ 4.Kennbuchstabe / 4 <sup>th</sup> letter O	$t_q$	typ.	550	$\mu s$
Sperrverzögerungsladung recovered charge	$T_{vj} = T_{vj\ max}$ $i_{TM} = I_{TAVM}$ , $-di_T/dt = 10\ A/\mu s$ $V_R = 0,5V_{RRM}$ , $V_{RM} = 0,8V_{RRM}$	$Q_f$	max.	15	mAs
Rückstromspitze peak reverse recovery current	$T_{vj} = T_{vj\ max}$ $i_{TM} = I_{TAVM}$ , $-di_T/dt = 10\ A/\mu s$ $V_R = 0,5V_{RRM}$ , $V_{RM} = 0,8V_{RRM}$	$I_{RM}$	max.	350	A

**Thermische Eigenschaften / Thermal properties**

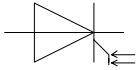
Innerer Wärmewiderstand thermal resistance, junction to case	<u>Kühlfläche / cooling surface</u> beidseitig / two-sided, $\theta = 180^\circ\ sin$ beidseitig / two-sided, DC Anode / anode, DC Kathode / cathode, DC	$R_{thJC}$	max.	0,0063	$^\circ C/W$
Übergangs-Wärmewiderstand thermal resistance, case to heatsink	<u>Kühlfläche / cooling surface</u> beidseitig / two-sided einseitig / single-sided	$R_{thCH}$	max.	0,0015	$^\circ C/W$
Höchstzulässige Sperrschichttemperatur maximum junction temperature		$T_{vj\ max}$		120	$^\circ C$
Betriebstemperatur operating temperature		$T_{c\ op}$		-40...+120	$^\circ C$
Lagertemperatur storage temperature		$T_{stg}$		-40...+150	$^\circ C$

**Mechanische Eigenschaften / Mechanical properties**

Gehäuse, siehe Anlage case, see annex				Seite 3 page 3	
Si-Element mit Druckkontakt Si-pellet with pressure contact					
Anpresskraft clamping force		F		63...91	kN
Gewicht weight		G	typ.	3200	g
Kriechstrecke creepage distance				49	mm
Schwingfestigkeit vibration resistance	f = 50 Hz			50	m/s <sup>2</sup>

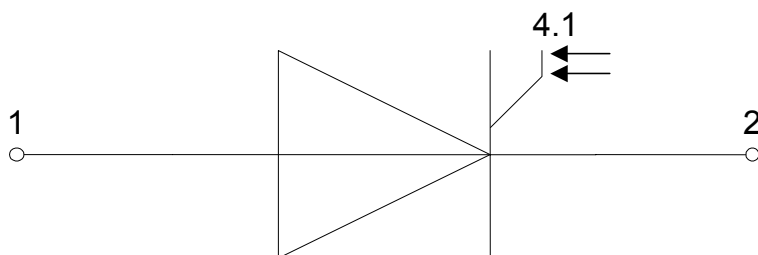
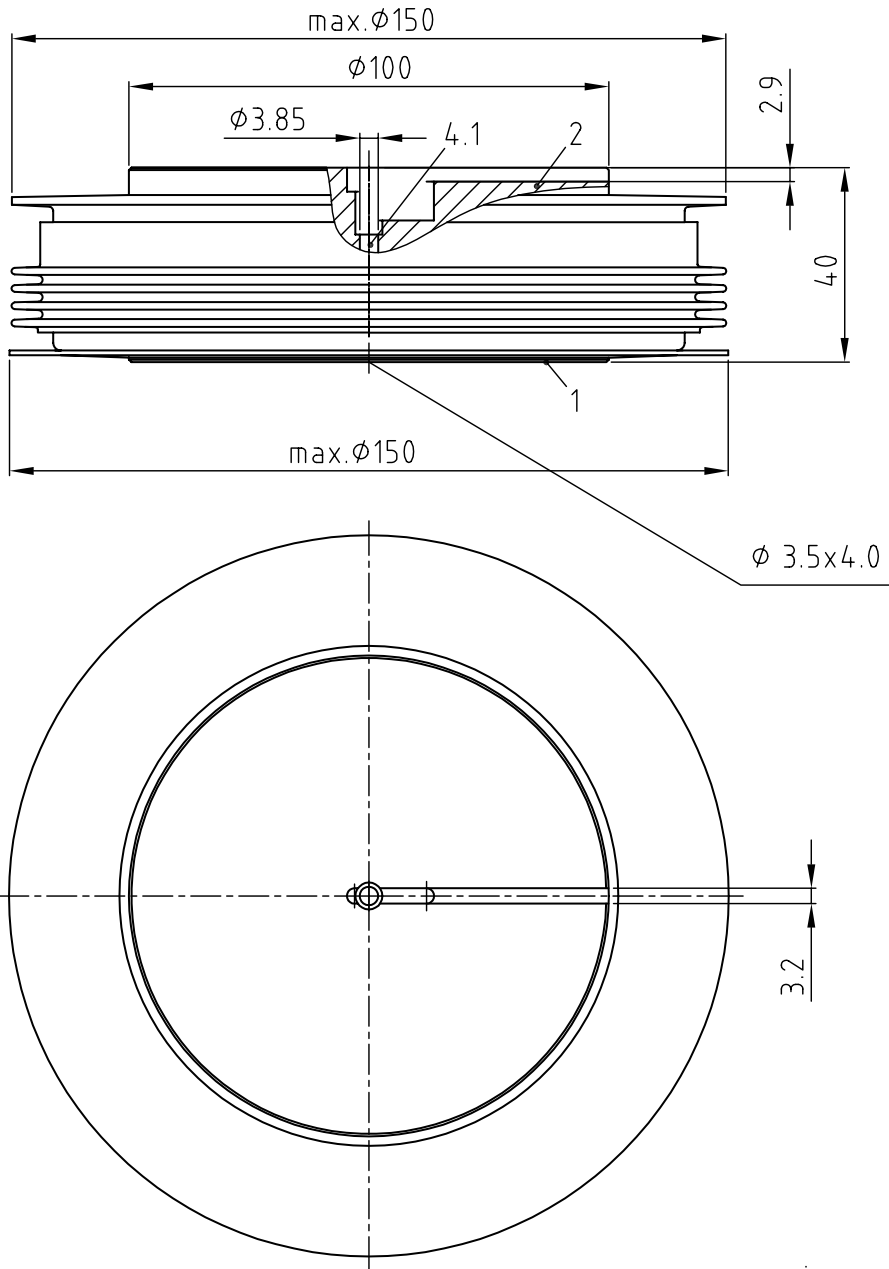
Mit diesem Datenblatt werden Halbleiterbauelemente spezifiziert, jedoch keine Eigenschaften zugesichert. Sie gilt in Verbindung mit den zugehörigen technischen Erläuterungen.

This data sheet specifies semiconductor devices, but promises no characteristics. It is valid in combination with the belonging technical notes.

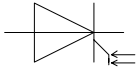


**Netz-Thyristor  
Phase Control Thyristor**

**T1503N**



- 1: Anode/Anode**
- 2: Kathode/Cathode**
- 4.1: Gate**



Netz-Thyristor  
Phase Control Thyristor

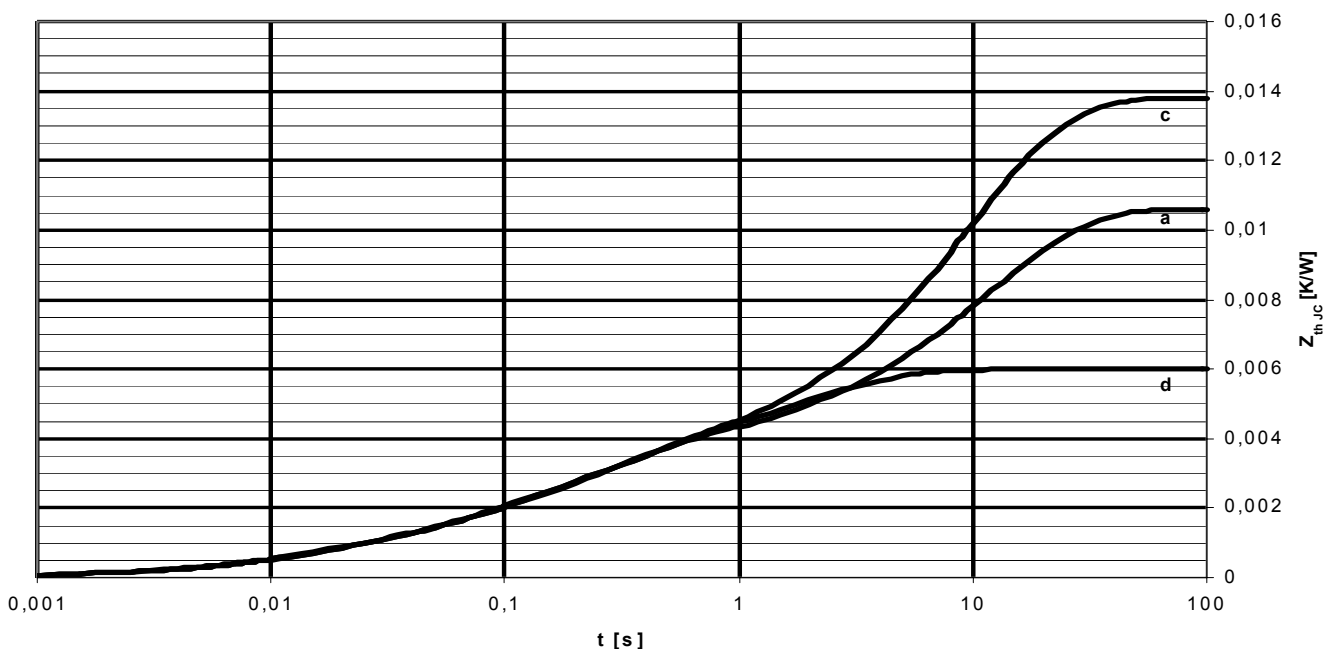
**T1503N**

Analytische Elemente des transienten Wärmewiderstandes  $Z_{thJC}$   
Analytical elements of transient thermal impedance  $Z_{thJC}$

	Pos. n	1	2	3	4	5	6	7
beidseitig two-sided	$R_{thn}$ [ $^{\circ}C/W$ ]	0,00238	0,00202	0,00110	0,0005	0		
	$\tau_n$ [s]	2,06	0,301	0,0674	0,0122	1		
anodenseitig anode-sided	$R_{thn}$ [ $^{\circ}C/W$ ]	0,00662	0,00043	0,00248	0,00081	0,00026		
	$\tau_n$ [s]	11,6	0,946	0,219	0,0310	0,00761		
kathodenseitig cathode-sided	$R_{thn}$ [ $^{\circ}C/W$ ]	0,0102	0,00224	0,00092	0,00044	0		
	$\tau_n$ [s]	9,62	0,268	0,0532	0,0107	1		

Analytische Funktion / Analytical function:

$$Z_{thJC} = \sum_{n=1}^{n_{max}} R_{thn} \left( 1 - e^{-\frac{t}{\tau_n}} \right)$$

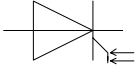


Transienter innerer Wärmewiderstand für DC/ Transient thermal impedance  $Z_{thJC} = f(t)$  for DC

Beidseitige Kühlung / Two-sided cooling

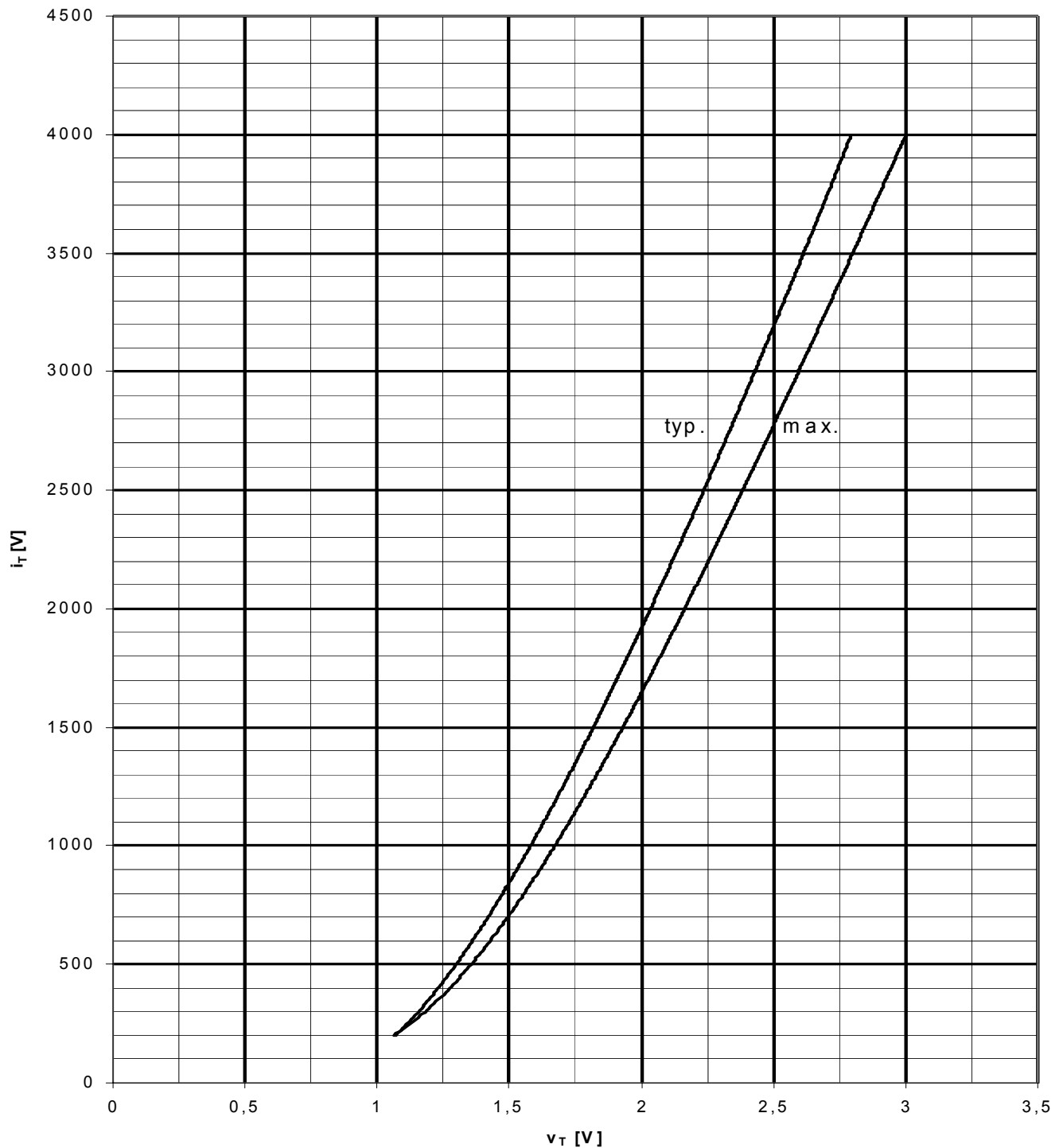
Anodenseitige Kühlung / Anode-sided cooling

Kathodenseitige Kühlung / Cathode-sided cooling



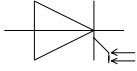
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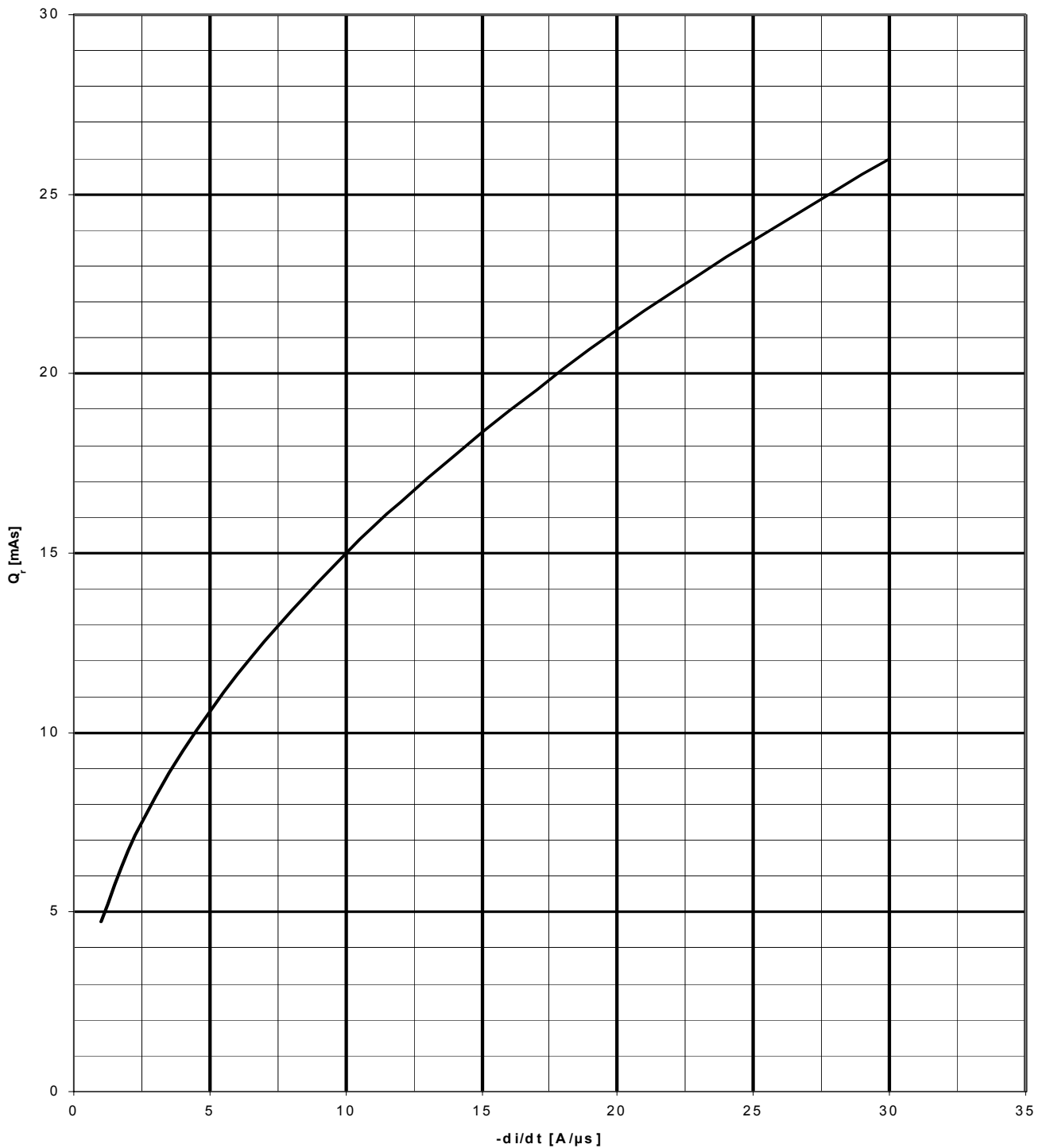
Grenzdurchlaßkennlinie / Limiting on-state characteristic  $i_T = f(v_T)$

$$T_{vj} = T_{vj \max}$$



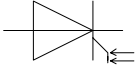
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**T1503N**



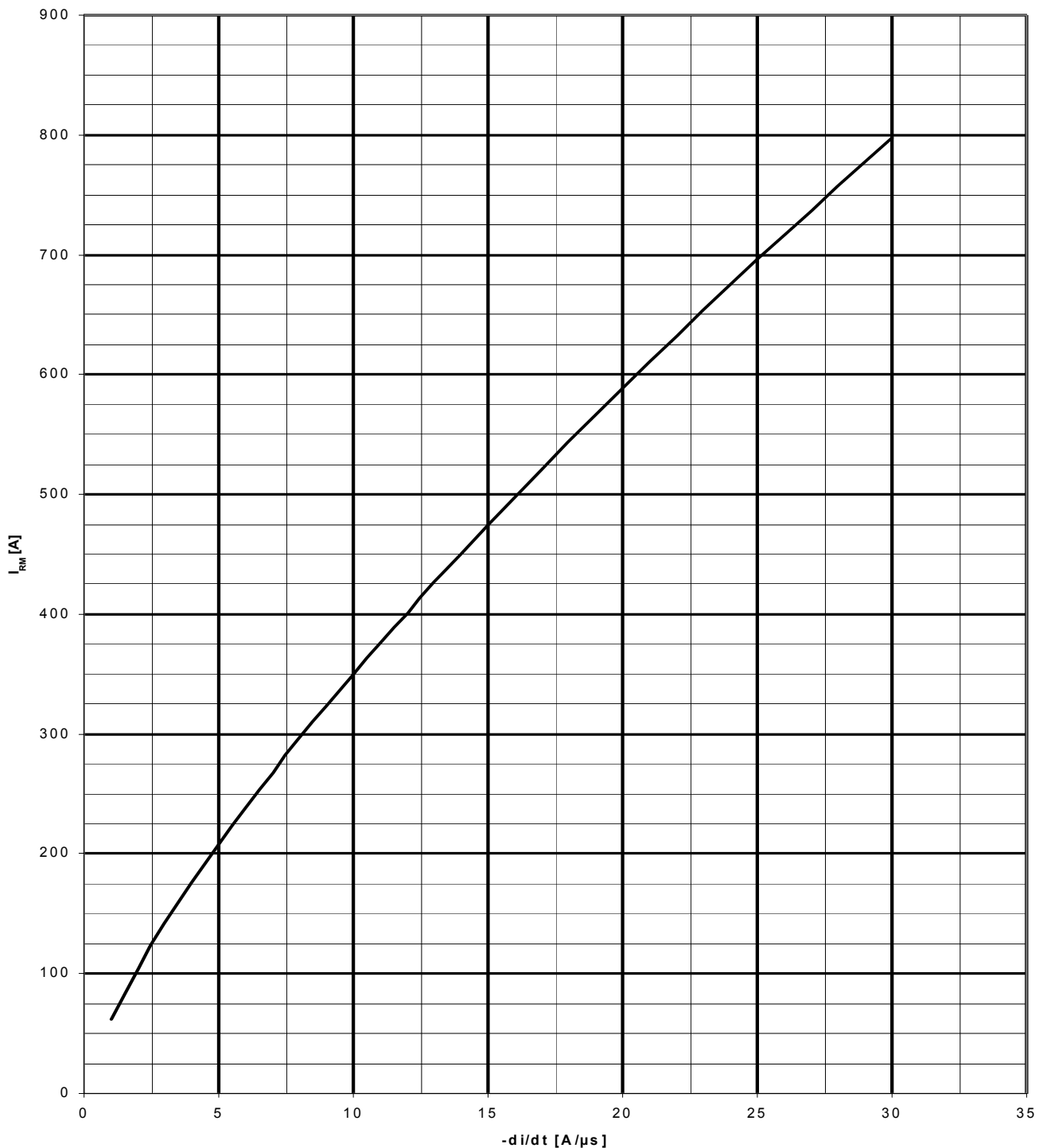
Sperrverzögerungsladung / Recovered charge  $Q_r = f(-di/dt)$

$$T_{vj} = T_{vjmax}, V_R = 0,5 V_{RRM}, V_{RM} = 0,8 V_{RRM}$$



Netz-Thyristor  
Phase Control Thyristor

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Rückstromspitze / Peak reverse recovery current  $I_{RM} = f(-di/dt)$

$$T_{vj} = T_{vjmax}, V_R = 0,5 V_{RRM}, V_{RM} = 0,8 V_{RRM}$$

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